



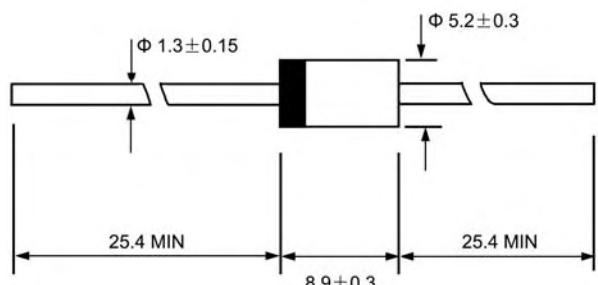
**VOLTAGE RANGE: 200--- 600 V**  
**CURRENT: 3.5 , 2.0 A**

## Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropanol and similar solvents

## Mechanical Data

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15grams
- ◇ Mounting: Any



Dimensions in millimeters

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		RU30Z	RU30	RU30A	UNITS
Maximum peak repetitive reverse voltage	$V_{RRM}$	200	400	600	V
Maximum RMS voltage	$V_{RMS}$	140	280	420	V
Maximum DC blocking voltage	$V_{DC}$	200	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	3.5		2.0	A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	$I_{FSM}$	80.0		200.0	A
Maximum instantaneous forward voltage @ $I_F=I_{F(AV)}$	$V_F$	0.97		0.95	V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$		10.0 300.0		$\mu\text{A}$
Maximum reverse recovery time (Note1)	$t_{rr}$		100		ns
Typical junction capacitance (Note2)	$C_J$		70	50	pF
Typical thermal resistance (Note3)	$R_{\theta JL}$		10		$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$		- 55 ----- + 150		$^\circ\text{C}$
Storage temperature range	$T_{STG}$		- 55 ----- + 150		$^\circ\text{C}$

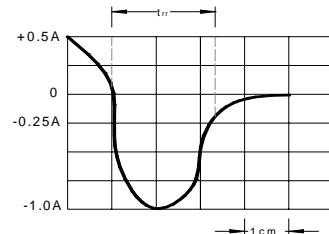
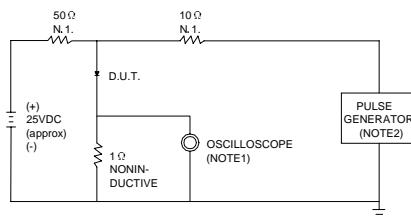
NOTE: 1. Measured with  $I_F=0.5\text{A}$  ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient

## Ratings AND Characteristic Curves

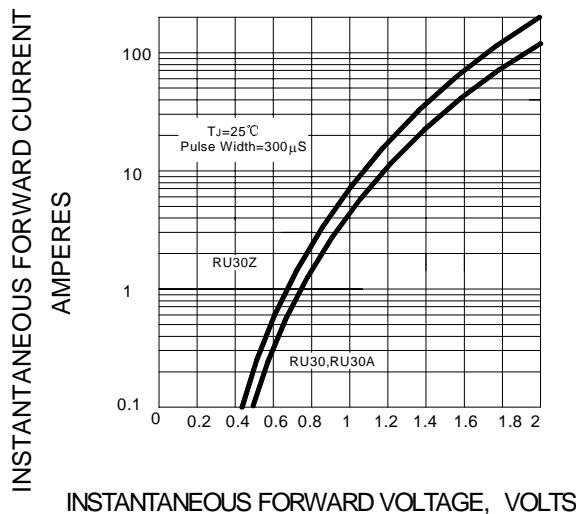
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



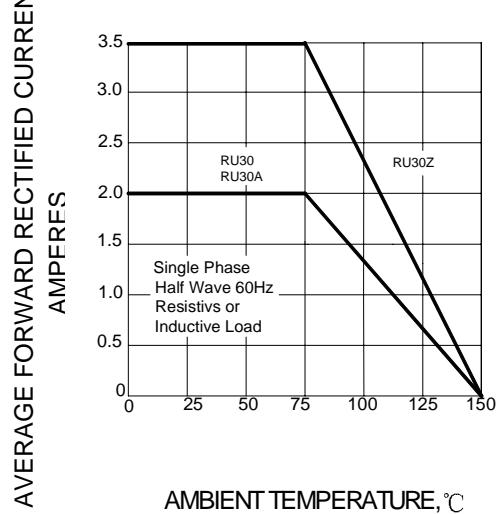
NOTES:  
1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ, 22pF.  
2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 10/20 ns/cm

**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



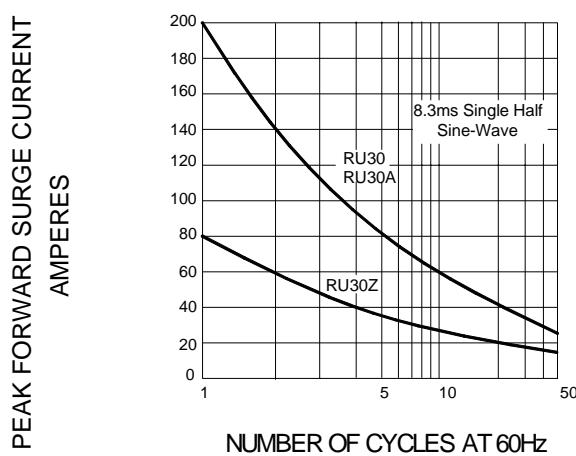
**FIG.3 – FORWARD DERATING CURVE**



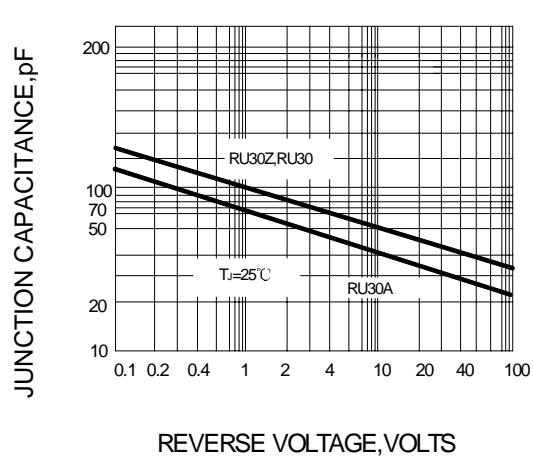
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

AMBIENT TEMPERATURE, °C

**FIG.4 – PEAK FORWARD SURGE CURRENT**



**FIG.5 – TYPICAL JUNCTION CAPACITANCE**



NUMBER OF CYCLES AT 60Hz

REVERSE VOLTAGE, VOLTS